

PS9001

HIGH CMR, 10 Mbps OPEN COLLECTOR OUTPUT TYPE, 5-PIN SOP (LSO5 WITH 8mm CREEPAGE DISTANCE) PHOTOCOUPLER

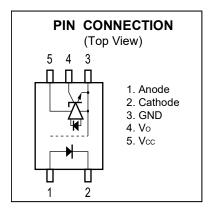
R08DS0130EJ0101 Rev.1.01 Oct 29, 2018

DESCRIPTION

The PS9001 is an optically coupled high-speed, active low type isolator containing an AlGaAs LED on the input side and a photodiode and a signal processing circuit on the output side on one chip.

FEATURES

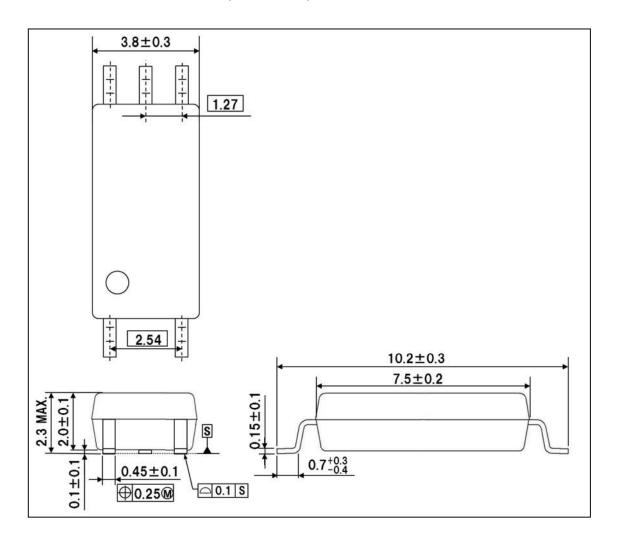
- Long creepage distance (8 mm MIN)
- High common mode transient immunity (CM_H, CM_L = ± 50 kV/ μ s MIN.)
- Operating Ambient Temperature (125 °C MAX.)
- High-speed response (t_{PHL} = 100 ns MAX., t_{PLH} = 100 ns MAX.)
- Embossed tape product : PS9001-F3: 3000 pcs/reel
- Pb-Free product
- · Safety standards
 - UL approved: UL1577, Double protection
 - CSA approved: CAN/CSA-C22.2 No. 62368-1, Reinforced insulation
 - VDE approved: DIN EN 60747-5-5 (Option)



APPLICATIONS

- Measurement equipment
- FA Network

PACKAGE DIMENSIONS (UNIT: mm)

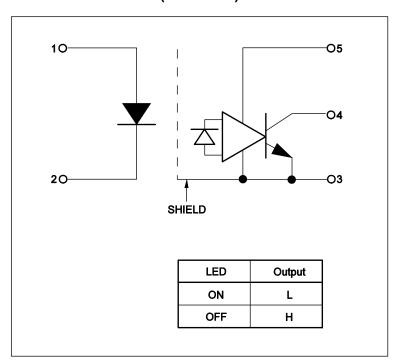


Weight: 0.119g (typ.)

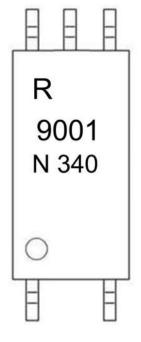
PHOTOCOUPLER CONSTRUCTION

Parameter	MIN.
Air Distance	8.0 mm
Creepage Distance	8.0 mm
Isolation Distance	0.15 mm

BLOCK DIAGRAM (Unit: mm)



MARKING EXAMPLE



R		An i	An initial of "Renesas"					
9001		Product Part Number				Product Part Number		
0		No.1 pin Mark, Anode Mark						
N340	N	Rank Code						
340		Ass	embly Lot					
		3	Last one-digit of Assembly Year					
		40	Weekly Serial Code					

ORDERING INFORMATION

Part Number	Order Number	Solder Plating Specification	Packing Style	Safety Standard Approval	Application Part Number*1
PS9001	PS9001-Y-AX	Pb-Free and	20 pcs (Tape 20 pcs cut)	Standard products	PS9001
PS9001-F3	PS9001-Y-F3-AX	Halogen Free (Ni/Pd/Au)	Embossed Tape 3 000 pcs/reel	(UL, CSA approved)	
PS9001-V	PS9001-Y-V-AX		20 pcs (Tape 20 pcs cut)	UL, CSA,	
PS9001-V-F3	PS9001-Y-V-F3-AX		Embossed Tape 3 000	DIN EN 60747-5-5	
			pcs/reel	approved	

Note: *1. For the application of the Safety Standard, following part number should be used.

ABSOLUTE MAXIMUM RATINGS (T_A = 25°C, unless otherwise specified)

	Parameter	Symbol	Ratings	Unit
Diode	Forward Current*1	l _F	25	mA
	Reverse Voltage	VR	5	V
Detector	Supply Voltage	Vcc	-0.5 to 7	V
	Output Voltage	Vo	-0.5 to 7	V
	Output Current	lo	20	mA
	Power Dissipation	Pc	100	mW
Isolation Volt	age *2	BV	5000	Vr.m.s.
Operating Ambient Temperature		TA	-40 to +125	°C
Storage Temperature		T _{stg}	−55 to +150	°C

Notes: *1. Reduced to 0.325 mA/ $^{\circ}$ C at T_A = 85 $^{\circ}$ C or more.

RECOMMENDED OPERATING CONDITIONS

Parameter	Symbol	MIN.	TYP.	MAX.	Unit
High Level Input Voltage	VF	-2	_	8.0	V
Low Level Input Current	I _F	8	10	12	mA
Supply Voltage	Vcc	4.5	5.0	5.5	V
Operating Ambient Temperature	T _A	-40	_	125	°C

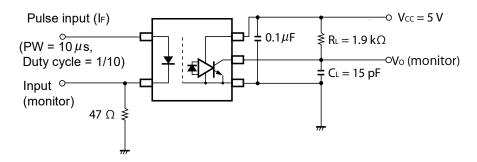
^{*2.} AC voltage for 1 minute at T_A = 25°C, RH = 60% between input and output. Pins 1-2 shorted together, 3-5 shorted together.

ELECTRICAL CHARACTERISTICS (T_A = -40 to +125°C, Vcc=5V unless otherwise specified)

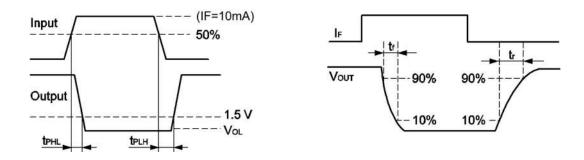
	Parameter	Symbol	Conditions	MIN.	TYP.*1	MAX.	Unit
Diode	Forward Voltage	V _F	I _F = 10 mA, T _A = 25°C	1.35	1.56	1.75	V
	Reverse Current	I _R	V _R = 3 V, T _A = 25°C			10	μА
	Terminal Capacitance	Ct	f = 1 MHz, V _F = 0 V, T _A = 25°C		30		pF
Detector	High Level Output Current	Іон	$V_{CC} = V_O = 5.5 \text{ V}, V_F = 0.8 \text{ V}$			50	μA
	Low Level Output Voltage	V _{OL}	I _F = 4 mA, I _{OL} = 5 mA		0.1	0.6	V
	High Level Supply Current	Іссн	$V_{CC} = 5.5 \text{ V}, I_F = 0 \text{ mA}, V_O = \text{open}$		1.4	2.0	mA
	Low Level Supply Current	Iccl	$V_{CC} = 5.5 \text{ V}, I_F = 10\text{mA},$ $V_O = \text{open}$		1.4	2.0	mA
Coupled	Threshold Input Voltage $(H \rightarrow L)$	I _{FHL}	V _O = 0.6V,I _O = 5mA		1.2	4.0	mA
	Propagation Delay Time $(H \rightarrow L)^{*2}$	t _{PHL}	I_F = 10 mA, R_L = 1.9 k Ω, C_L = 15 pF,		35	100	ns
	Propagation Delay Time $(L \rightarrow H)^{*2}$	t _{PLH}	V _{THHL} = 1.5 V, V _{THLH} = 1.5 V		65	100	ns
	Pulse Width Distortion (PWD)	t _{PHL} -			30	50	ns
	Propagation Delay Skew	t _{psk}				60	ns
	Common Mode Transient Immunity at High Level Output *3	СМн	$T_A = 25^{\circ}\text{C},$ $I_F = 0 \text{ mA}, V_O > 1.5 \text{ V},$ $R_L = 1.9 \text{ k}\Omega, V_{CM} = 1.5 \text{ kV},$ $C_L = 15 \text{ pF}$	50			kV/μs
Transient	Common Mode Transient Immunity at Low Level Output *3	CM∟	$T_{A} = 25^{\circ}C,$ $I_{F} = 10 \text{ mA, V}_{O} < 1.5 \text{ V},$ $R_{L} = 1.9 \text{ k}\Omega, V_{CM} = 1.5 \text{ kV},$ $C_{L} = 15 \text{ pF}$	50			kV/μs

Notes: *1. Typical values at $T_A = 25$ °C

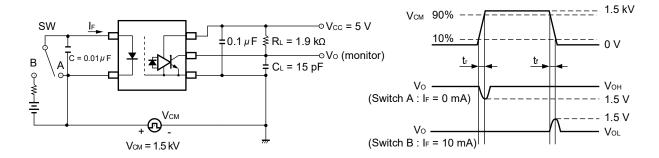
*2. Test circuit for tPHL and tPLH



Remark C_L includes probe and stray wiring capacitance.

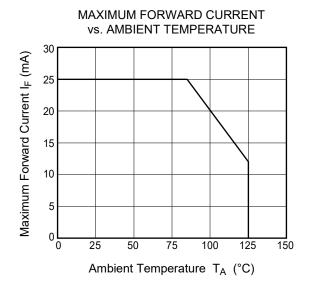


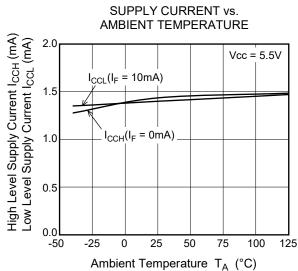
*3. Test circuit for common mode transient immunity

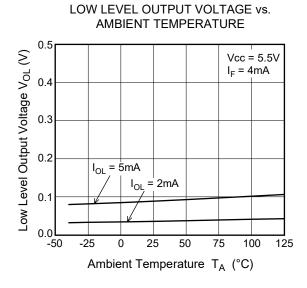


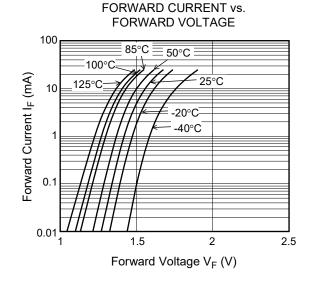
Remark C_L includes probe and stray wiring capacitance.

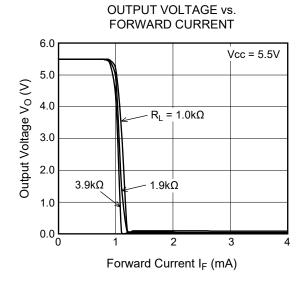
TYPICAL CHARACTERISTICS (T_A = 25°C, unless otherwise specified)

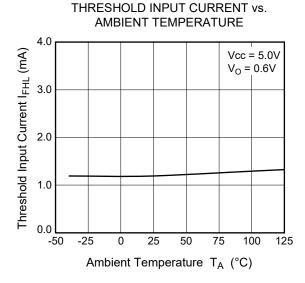






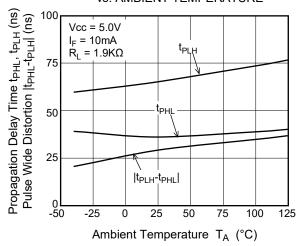




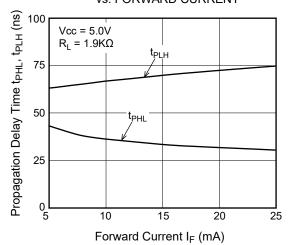


Remark The graphs indicate nominal characteristics.

PROPAGATION DELAY TIME, PULSE WIDE DISTORTION vs. AMBIENT TEMPERATURE

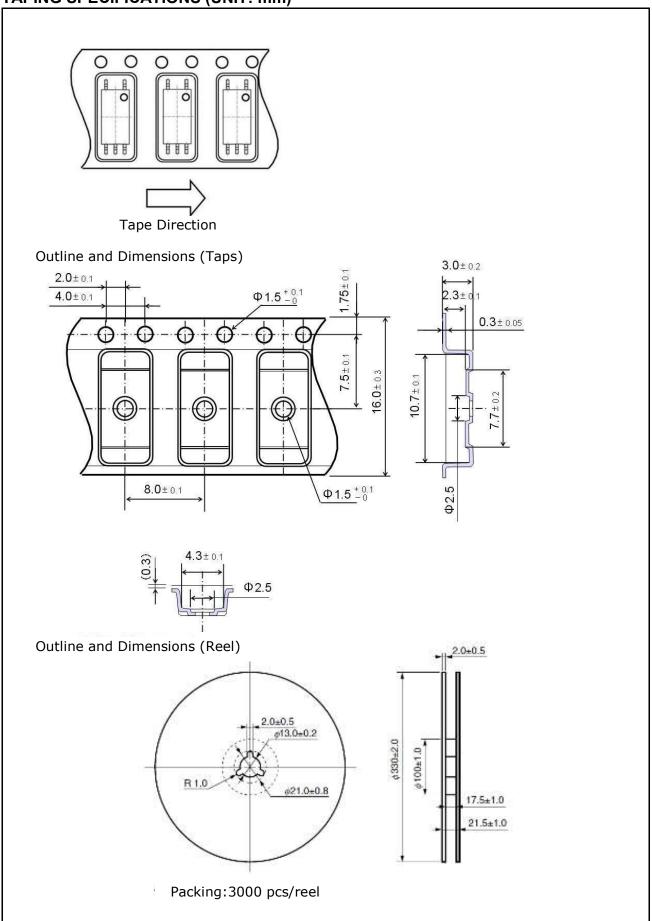


PROPAGATION DELAY TIME vs. FORWARD CURRENT

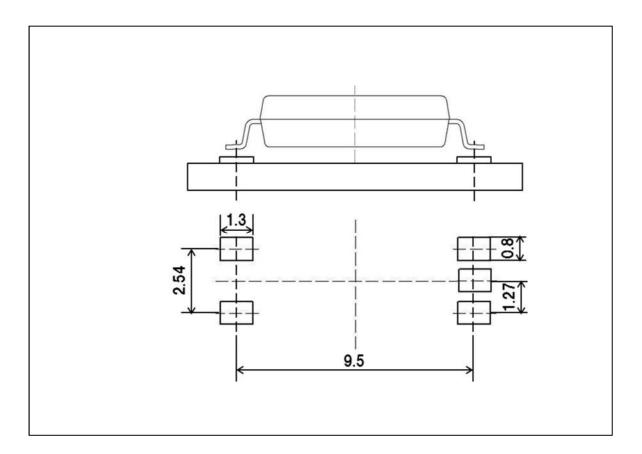


Remark The graphs indicate nominal characteristics.

TAPING SPECIFICATIONS (UNIT: mm)



RECOMMENDED MOUNT PAD DIMENSIONS (UNIT: mm)



Remark All dimensions in this figure must be evaluated before use.

NOTES ON HANDLING

- 1. Recommended soldering conditions
 - (1) Infrared reflow soldering

Peak reflow temperature 260°C or below (package surface temperature)

Time of peak reflow temperature 10 seconds or less Time of temperature higher than 220°C 60 seconds or less

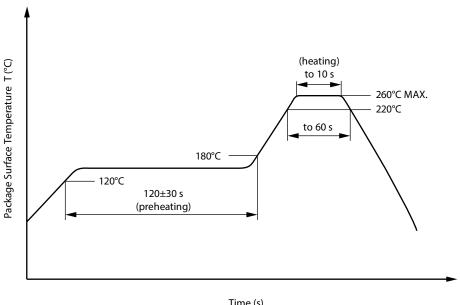
120±30 s Time to preheat temperature from 120 to 180°C Number of reflows Three

Flux Rosin flux containing small amount of chlorine (The flux

with a maximum chlorine content of 0.2 Wt% is

recommended.)

Recommended Temperature Profile of Infrared Reflow



Time (s)

(2) Wave soldering

Temperature 260°C or below (molten solder temperature)

Time 10 seconds or less

Preheating conditions 120°C or below (package surface temperature)

Number of times One (Allowed to be dipped in solder including plastic mold portion.)

Flux Rosin flux containing small amount of chlorine (The flux with a maximum chlorine

content of 0.2 Wt% is recommended.)

(3) Soldering by Soldering Iron

Peak Temperature (lead part temperature) 350°C or below

Time (each pins) 3 seconds or less

Flux Rosin flux containing small amount of chlorine (The flux with a

maximum chlorine content of 0.2 Wt% is recommended.)

(a) Soldering of leads should be made at the point 1.5 to 2.0 mm from the root of the lead

(4) Cautions

 Fluxes Avoid removing the residual flux with freon-based and halogens-based (chlorine-based) cleaning solvent.

2. Cautions regarding noise

Be aware that when voltage is applied suddenly between the photocoupler's input and output at startup, the output transistor may enter the on state, even if the voltage is within the absolute maximum ratings.

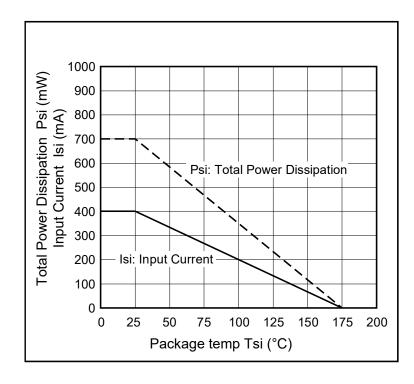
USAGE CAUTIONS

- 1. This product is weak for static electricity by designed with high-speed integrated circuit so protect against static electricity when handling.
- 2. By-pass capacitor of more than $0.1~\mu F$ is used between V_{CC} and GND near device. Also, ensure that the distance between the leads of the photocoupler and capacitor is no more than 10~mm.
- 3. Avoid storage at a high temperature and high humidity.
- 4. Do not use adhesives or coating materials including halogens to fix this device.

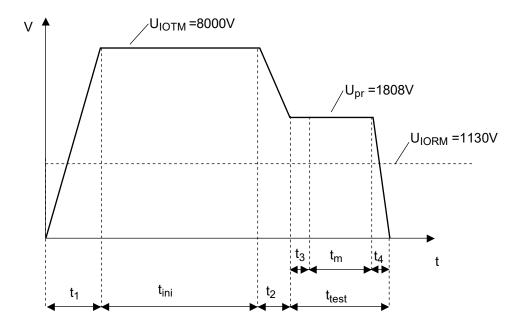
SPECIFICATION OF VDE MARKS LICENSE DOCUMENT

Parameter	Symbol	Rating	Unit
Climatic test class (IEC 60068-1/DIN EN 60068-1)		40/125/21	
Dielectric strength			
maximum operating isolation voltage	U_IORM	1 130	V_{peak}
Test voltage (partial discharge test, procedure a for type test and random test)	U_pr	1 808	V_{peak}
$U_{pr} = 1.6 \times U_{IORM.}, P_d < 5 pC$			
Test voltage (partial discharge test, procedure b for all devices)	U_pr	2 119	V_{peak}
$U_{pr} = 1.875 \times U_{IORM.}, P_d < 5 pC$			
Highest permissible overvoltage	U _{TR}	8 000	V_{peak}
Degree of pollution (DIN EN 60664-1 VDE0110 Part 1)		2	
Comparative tracking index (IEC 60112/DIN EN 60112 (VDE 0303 Part 11))	CTI	400	
Material group (DIN EN 60664-1 VDE0110 Part 1)		П	
Storage temperature range	T _{stg}	-55 to +150	°C
Operating temperature range	TA	-40 to +125	°C
Isolation resistance, minimum value			
V _{IO} = 500 V dc at T _A = 25°C	Ris MIN.	10 ¹²	Ω
V _{IO} = 500 V dc at T _A MAX. at least 100°C	Ris MIN.	10 ¹¹	Ω
Safety maximum ratings (maximum permissible in case of fault, see thermal			
derating curve)			
Package temperature	Tsi	175	°C
Current (input current I _F , Psi = 0)	lsi	400	mA
Power (output or total power dissipation)	Psi	700	mW
Isolation resistance			
V _{IO} = 500 V dc at T _A = Tsi	Ris MIN.	10 ⁹	Ω

Dependence of maximum safety ratings with package temperature

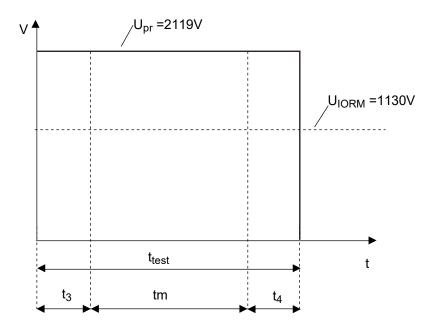


Method a) Destructive Test, Type and Sample Test



 $t_1, t_2 = 1 \text{ to } 10 \text{ sec}$ $t_3, t_4 = 1 \text{ sec}$ $t_{m(PARTIAL\ DISCHARGE)}$ = 10 sec $t_{\text{test}} = 12 \text{ sec}$ $t_{\text{ini}} = 60 \text{ sec}$

Method b) Non-destructive Test, 100% Production Test



 $t_3, t_4 = 0.1 \text{ sec}$ $t_{m(PARTIAL\ DISCHARGE)} = 1.0\ sec$ $t_{test} = 1.2 sec$

Caution

GaAs Products

This product uses gallium arsenide (GaAs).

GaAs vapor and powder are hazardous to human health if inhaled or ingested, so please observe the following points.

- Follow related laws and ordinances when disposing of the product. If there are no applicable laws and/or ordinances, dispose of the product as recommended below.
 - 1. Commission a disposal company able to (with a license to) collect, transport and dispose of materials that contain arsenic and other such industrial waste materials.
- 2. Exclude the product from general industrial waste and household garbage, and ensure that the product is controlled (as industrial waste subject to special control) up until final disposal.
- Do not burn, destroy, cut, crush, or chemically dissolve the product.
- Do not lick the product or in any way allow it to enter the mouth.

Notice

- 1. Descriptions of circuits, software and other related information in this document are provided only to illustrate the operation of semiconductor products and application examples. You are fully responsible for the incorporation or any other use of the circuits, software, and information in the design of your product or system. Renesas Electronics disclaims any and all liability for any losses and damages incurred by you or third parties arising from the use of these circuits, software, or information.
- 2. Renesas Electronics hereby expressly disclaims any warranties against and liability for infringement or any other claims involving patents, copyrights, or other intellectual property rights of third parties, by or arising from the use of Renesas Electronics products or technical information described in this document, including but not limited to, the product data, drawings, charts, programs, algorithms, and application
- 3. No license, express, implied or otherwise, is granted hereby under any patents, copyrights or other intellectual property rights of Renesas Electronics or others.
- 4. You shall not alter, modify, copy, or reverse engineer any Renesas Electronics product, whether in whole or in part. Renesas Electronics disclaims any and all liability for any losses or damages incurred by you or third parties arising from such alteration, modification, copying or reverse engineering.
- 5. Renesas Electronics products are classified according to the following two quality grades: "Standard" and "High Quality". The intended applications for each Renesas Electronics product depends on the product's quality grade, as indicated below.
 - Computers; office equipment; communications equipment; test and measurement equipment; audio and visual equipment; home electronic appliances; machine tools; personal electronic equipment; industrial robots; etc.
 - "High Quality": Transportation equipment (automobiles, trains, ships, etc.); traffic control (traffic lights); large-scale communication equipment; key financial terminal systems; safety control equipment; etc. Unless expressly designated as a high reliability product or a product for harsh environments in a Renesas Electronics data sheet or other Renesas Electronics document, Renesas Electronics products are not intended or authorized for use in products or systems that may pose a direct threat to human life or bodily injury (artificial life support devices or systems; surgical implantations; etc.), or may cause serious property damage (space system; undersea repeaters; nuclear power control systems; aircraft control systems; key plant systems; military equipment; etc.). Renesas Electronics disclaims any and all liability for any damages or losses incurred by you or any third parties arising from the use of any Renesas Electronics product that is inconsistent with any Renesas Electronics data sheet, user's manual or other Renesas Electronics document.
- 6. When using Renesas Electronics products, refer to the latest product information (data sheets, user's manuals, application notes, "General Notes for Handling and Using Semiconductor Devices" in the reliability handbook, etc.), and ensure that usage conditions are within the ranges specified by Renesas Electronics with respect to maximum ratings, operating power supply voltage range, heat dissipation characteristics, installation, etc. Renesas Electronics disclaims any and all liability for any malfunctions, failure or accident arising out of the use of Renesas Electronics products outside of such specified
- 7. Although Renesas Electronics endeavors to improve the quality and reliability of Renesas Electronics products, semiconductor products have specific characteristics, such as the occurrence of failure at a certain rate and malfunctions under certain use conditions. Unless designated as a high reliability product or a product for harsh environments in a Renesas Electronics data sheet or other Renesas Electronics document, Renesas Electronics products are not subject to radiation resistance design. You are responsible for implementing safety measures to guard against the possibility of bodily injury, injury or damage caused by fire, and/or danger to the public in the event of a failure or malfunction of Renesas Electronics products, such as safety design for hardware and software, including but not limited to redundancy, fire control and malfunction prevention, appropriate treatment for aging degradation or any other appropriate measures. Because the evaluation of microcomputer software alone is very difficult and impractical, you are responsible for evaluating the safety of the final products or systems manufactured by you.
- 8. Please contact a Renesas Electronics sales office for details as to environmental matters such as the environmental compatibility of each Renesas Electronics product. You are responsible for carefully and sufficiently investigating applicable laws and regulations that regulate the inclusion or use of controlled substances, including without limitation, the EU RoHS Directive, and using Renesas Electronics products in compliance with all these applicable laws and regulations. Renesas Electronics disclaims any and all liability for damages or losses occurring as a result of your noncompliance with applicable
- 9. Renesas Electronics products and technologies shall not be used for or incorporated into any products or systems whose manufacture, use, or sale is prohibited under any applicable domestic or foreign laws or regulations. You shall comply with any applicable export control laws and regulations promulgated and administered by the governments of any countries asserting jurisdiction over the parties or
- 10. It is the responsibility of the buyer or distributor of Renesas Electronics products, or any other party who distributes, disposes of, or otherwise sells or transfers the product to a third party, to notify such third party in advance of the contents and conditions set forth in this document.
- 11. This document shall not be reprinted, reproduced or duplicated in any form, in whole or in part, without prior written consent of Renesas Electronics
- 12. Please contact a Renesas Electronics sales office if you have any questions regarding the information contained in this document or Renesas Electronics products.
- (Note 1) "Renesas Electronics" as used in this document means Renesas Electronics Corporation and also includes its directly or indirectly controlled subsidiaries
- (Note 2) "Renesas Electronics product(s)" means any product developed or manufactured by or for Renesas Electronics

(Rev.4.0-1 November 2017)



SALES OFFICES

Renesas Electronics Corporation

http://www.renesas.com

Refer to "http://www.renesas.com/" for the latest and detailed information.

California Eastern Laboratories, Inc. 4590 Patrick Henry Drive, Santa Clara, California 95054-1817, U.S.A. Tel: +1-408-919-2500, Fax: +1-408-988-0279

Renesas Electronics Europe Limited
Dukes Meadow, Millboard Road, Bourne End, Buckinghamshire, SL8 5FH, U.K
Tel: +44-1628-651-700, Fax: +44-1628-651-804

Renesas Electronics Europe GmbH Arcadiastrasse 10, 40472 Düsseldorf, Germany Tel: +49-211-6503-0, Fax: +49-211-6503-1327

Renesas Electronics (China) Co., Ltd.
Room 1709 Quantum Plaza, No.27 ZhichunLu, Haidian District, Beijing, 100191 P. R. China Tel: +86-10-8235-1155, Fax: +86-10-8235-7679

Renesas Electronics (Shanghai) Co., Ltd.
Unit 301, Tower A, Central Towers, 555 Langao Road, Putuo District, Shanghai, 200333 P. R. China Tel: +86-21-2226-0888, Fax: +86-21-2226-0999

Renesas Electronics Hong Kong Limited
Unit 1601-1611, 16/F., Tower 2, Grand Century Place, 193 Prince Edward Road West, Mongkok, Kowloon, Hong Kong Tel: +852-2265-6688, Fax: +852 2886-9022

Renesas Electronics Taiwan Co., Ltd. 13F, No. 363, Fu Shing North Road, Taipei 10543, Taiwan Tel: +886-2-8175-9600, Fax: +886 2-8175-9670

Renesas Electronics Singapore Pte. Ltd. 80 Bendemeer Road, Unit #166-02 Hyflux Innovation Centre, Singapore 339949 Tel: +65-6213-0200, Fax: +65-6213-0300

Renesas Electronics Malaysia Sdn.Bhd.

Unit 1207, Block B, Menara Amcorp, Amcorp Trade Centre, No. 18, Jln Persiaran Barat, 46050 Petaling Jaya, Selangor Darul Ehsan, Malaysia Tel: +60-3-7955-9390, Fax: +60-3-7955-9510

Renesas Electronics India Pvt. Ltd. No.777C, 100 Feet Road, HAL 2nd Stage, Indiranagar, Bangalore 560 038, India Tel: +91-80-67208700, Fax: +91-80-67208777

Renesas Electronics Korea Co., Ltd.
17F, KAMCO Yangjae Tower, 262, Gangnam-daero, Gangnam-gu, Seoul, 06265 Korea
Tel: +82-2-558-3737, Fax: +82-2-558-5338

© 2018 Renesas Electronics Corporation, All rights reserved.